

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IXTH270N04T4

D(2)

#### • FEATURES

Static drain-source on-resistance:

 $R_{DS}(on) \le 4.7 m_{\Omega} @V_{GS}=10V$ 

- · Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION

SYMBO

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VDSS

V<sub>GS</sub>

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**I**DM

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- DC/DC Converters
- High Current Switching Applications

Drain-Source Voltage

Gate-Source Voltage

Drain Current-Continuous

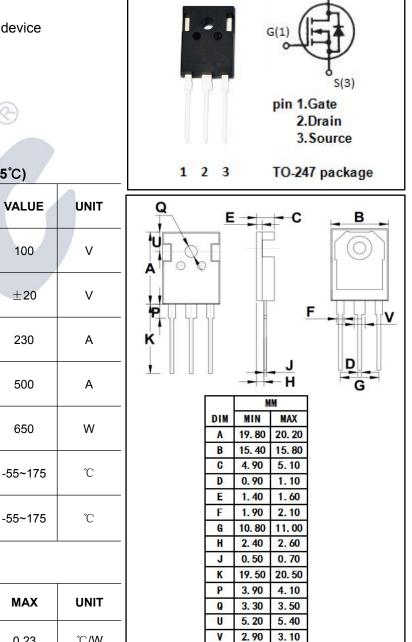
**Drain Current-Single Pulsed** 

Total Dissipation @Tc=25°C

**Operating Junction Temperature** 

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER



## THERMAL CHARACTERISTICS

Storage Temperature

SYMBO L	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.23	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	100		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 115A		4.7	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±200	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		50	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		3000	
Vsd	Diode forward voltage	I <sub>F</sub> = 100A; V <sub>GS</sub> = 0V		1.3	V

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